

# Critical microwave-conductivity fluctuations across the phase diagram of superconducting $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ thin films

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We report a systematic study of the dynamic microwave conductivity near  $T_c$  for  $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$  (LSCO) thin films with  $x=0.07$  to 0.16. The strong frequency dependence of the phase stiffness together with scaling analysis of the ac fluctuating conductivity of superconductivity provide direct evidence for the 2D-XY behavior of nearly decoupled  $\text{CuO}_2$  planes in underdoped LSCO ( $x=0.07$  and 0.12). On the other hand, the critical exponents for slightly overdoped LSCO ( $x=0.16$ ) were found to agree with those for the relaxational 3D-XY model, indicating that the universality class in LSCO is changed by hole doping. The implication of these results for the phase diagram of high- $T_c$  cuprates is discussed.

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One of the hallmarks of the high- $T_c$  cuprates is the large thermal fluctuation of the superconducting order enhanced by the short coherence length and the quasi two-dimensionality, which enables the exploration of the fluctuation-dominated critical regime very close to  $T_c$ <sup>1</sup>. Although numerous measurements, such as the ac conductivity<sup>2</sup>, the dc magnetization<sup>3</sup>, the specific heat<sup>4</sup>, and the  $I$ - $V$  curves<sup>5</sup>, have been performed to investigate the critical fluctuation, there has been no consensus among the results. This is surprising because the critical phenomena were considered to be universal, independent of the microscopic details<sup>6</sup>. However, if many assumptions were made implicitly to determine the universality class of the phase transition from the data, the obtained results are not convincing unless the validity of such assumptions is confirmed. Thus, one should develop a more reliable method which does not require any extra assumptions. To our knowledge, the most successful method is dynamic scaling analysis of the ac complex conductivity,  $\sigma(\omega) = \sigma_1(\omega) - i\sigma_2(\omega)$ , as will be discussed later.

Another fascinating hallmark of the high- $T_c$  cuprates is that the physical properties change with hole doping. In particular, an understanding of the phase diagram as a plot of  $T_c$  versus the hole concentration has been a central issue in the physics of high- $T_c$  cuprates. Interestingly, some recent models, which start from the quantum criticality for competing orders underlying the phase diagram of high- $T_c$  cuprates, provide another possible explanation for the critical fluctuations in high- $T_c$  cuprates. That is, the critical fluctuations change with hole doping, because of the existence of a quantum critical point (QCP)<sup>7</sup>. These models suggest that the critical dynamics should be investigated as a function of hole doping. Thus, it can be expected that such a systematic study across the phase diagram will not only resolve the disagreements among earlier studies but will also provide important information to understand the phase diagram of high- $T_c$  cuprates.

In this paper, we report a systematic study of  $\sigma(\omega)$  as a function of the swept-frequency (0.1 GHz to 12 GHz) for high-quality  $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$  (LSCO) thin films with a wide range of hole concentrations ( $x=0.07$  to 0.16). For underdoped (UD) LSCO, we show clear evidence for the 2D-XY critical fluctuation of nearly decoupled  $\text{CuO}_2$  planes. With increasing hole doping, a dimensional crossover from 2D-XY behavior to 3D-XY behavior was observed near  $x=0.16$ , implying that there are at least two universality classes in the phase diagram of LSCO.

Epitaxial LSCO thin films with  $x=0.07$ , 0.12 (underdoped), 0.14 (nearly optimally doped), and 0.16 (overdoped) were grown on  $\text{LaSrAlO}_4$  (001) substrates by a pulsed laser deposition technique using pure ozone<sup>8</sup>. All the films are highly  $c$ -axis oriented with a sufficiently narrow rocking curve of the 002 reflection (typically 0.2°). As shown in Table I, the value of the in-plane dc resistivity,  $\rho_{dc}$ , was found to agree with the reported best value for LSCO thin films<sup>9</sup> within a factor of 2, confirming that the films used in this study are of sufficiently high quality to investigate the critical dynamics near  $T_c$ .

There are three reasons for using LSCO films on  $\text{LaSrAlO}_4$  (LSAO) substrates in this study: (1) LSCO is an ideal system with a simple layered structure, where the hole concentration can be widely controlled. (2) The compressive epitaxial strain gives rise to a moderate increase of  $T_c$ <sup>9</sup>. (3) The tetragonal symmetry of LSAO

TABLE I: Values of  $t$ ,  $\rho_{dc}$ , and  $T_c$  for the measured films.  $\rho_{dc}$  is the value at  $T=50$  K. As for three kinds of  $T_c$ , see the text for definition.

| $x$  | $t$ (nm) | $\rho_{dc}$ (mΩcm) | $T_c^{\text{scale}}$ (K) | $T_c^0$ (K) | $T_{MF}$ (K) |
|------|----------|--------------------|--------------------------|-------------|--------------|
| 0.07 | 460      | 0.77               | 19.0                     | 20.83       | ~32          |
| 0.12 | 230      | 0.28               | 33.65                    | 36.08       | ~38          |
| 0.14 | 270      | 0.14               | 38.92                    | 39.29       | ~40          |
| 0.16 | 140      | 0.12               | 35.5                     | 35.82       | —            |

substrate supports the fabrication of  $\text{CuO}_2$  planes with ideal flat square lattices, free from disorders due to corrugations and twin boundaries<sup>8</sup>.

Both the real and imaginary parts of  $\sigma(\omega)$  were obtained from the complex reflection coefficient,  $S_{11}(\omega)$ , using a non-resonant broadband technique<sup>10</sup>. When the film thickness,  $t$ , is sufficiently less than the skin depth,  $\delta$ , one can write  $\sigma(\omega)$ , as follows,

$$\sigma(\omega) = \frac{1}{tZ_0} \frac{1 - S_{11}(\omega)}{1 + S_{11}(\omega)}, \quad (1)$$

where  $Z_0 = 377 \Omega$  is the impedance of free space. In practice, before applying Eq. (1), systematic errors involved in  $S_{11}(\omega)$  were carefully removed by calibration measurements using known standards<sup>10</sup>.

In order to obtain reliable  $\sigma(\omega)$  data, the effect of the dielectric substrate needs to be considered. Note that the choice of  $t$  according to values of  $\rho_{dc}$  is important, because a resonance peak attributed to the effect of substrate can be induced for a very small value of  $t$ <sup>11</sup>. In fact, a sharp resonance peak has been observed near 8 GHz for the LSCO film ( $x=0.07$ ) above 100 K<sup>10</sup>. However, in the data presented in Fig. 1, no peak was observed over the whole frequency range measured at lower temperatures near  $T_c$ . Thus, we can conclude that the effect of substrate was negligible near  $T_c$ .

Moreover, in the vicinity of  $T_c$ , we found that  $\sigma(\omega)$  was seriously affected by a small unexpected difference (typically,  $0.2^\circ$ - $0.3^\circ$  at 1 GHz) between the phase of  $S_{11}$  for a load standard,  $\angle S_{11}^{\text{load}}$ , and that for a short standard,  $\angle S_{11}^{\text{short}}$ . This difficulty was resolved by using the measured  $S_{11}(\omega)$  of the sample at a temperature far above  $T_c$  as the load standard, assuming that  $\angle S_{11}^{\text{short}} = \angle S_{11}^{\text{load}}$ .

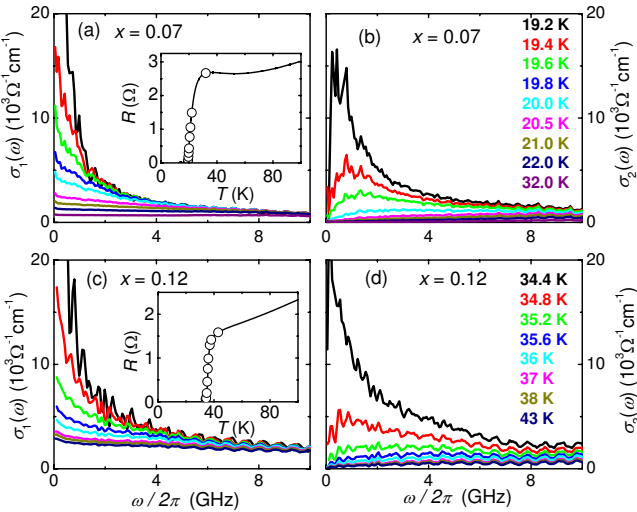


FIG. 1: The frequency dependence of (a)  $\sigma_1(\omega)$  for  $x=0.07$ , (b)  $\sigma_2(\omega)$  for  $x=0.07$ , (c)  $\sigma_1(\omega)$  for  $x=0.12$ , (d)  $\sigma_2(\omega)$  for  $x=0.12$ , respectively. Insets: the temperature dependence of the dc resistance,  $R$ , of the same sample. Open circles near  $T_c$  show  $R$  at the temperatures presented in the main panel.

at this temperature, and that both were  $T$ -independent in the vicinity of  $T_c$ . The validity of this procedure was also confirmed by the same measurements for NbN thin films as a reference<sup>12</sup>.

Figure 1 shows the frequency dependence of  $\sigma(\omega)$ , obtained by the above procedures, for underdoped LSCO ( $x=0.07$  and  $0.12$ ) at several temperatures above  $T_c$ . It is evident that both  $\sigma_1(\omega)$  and  $\sigma_2(\omega)$  diverge rapidly with decreasing temperature in the low frequency limit, suggesting that the excess conductivity is due to the superconducting fluctuations. A similar divergence in  $\sigma(\omega)$  was also observed in the vicinity of  $T_c$  for the other LSCO films.

It has been argued<sup>13</sup> that strong phase fluctuations are important for the determination of  $T_c$  in the UD region, because the phase-stiffness energy,  $k_B T_\theta \equiv (\hbar/e^2)\hbar\omega\sigma_2 d_s$ , is suppressed largely by the small superfluid density, where  $d_s$  is the effective thickness of a superfluid. Figure 2 shows the phase-stiffness temperature  $T_\theta(T)$  estimated from  $\sigma_2(\omega, T)$  at several frequencies. Surprisingly, we found that  $T_\theta(T)$  for the UD samples ( $x=0.07$  and  $0.12$ ) started to show frequency dependence above a certain temperature,  $T_k$ , while  $T_\theta(T)$  was almost  $\omega$ -independent below  $T_k$ . In addition, the resistive  $T_c$  ( $T_c^R$ ), where  $R$  became zero, was also close to  $T_k$  rather than another critical temperature,  $T_c^0$ , where the bare phase stiffness in the XY model would go to zero. When we assumed  $d_s$  to be approximately  $t/2$ , we saw that a dashed straight line with a slope of  $8/\pi$  crossed  $T_\theta(T)$  at  $T_k$ , indicating that  $T_k$  agrees with the Berezinskii-Kosterlitz-Thouless (BKT) transition temperature,  $T_{\text{BKT}}$ , in the 2D-XY model<sup>14,15</sup>.

As shown in Figs. 2(c) and 2(d), this behavior was observed even for  $x=0.14$ , while it disappeared almost

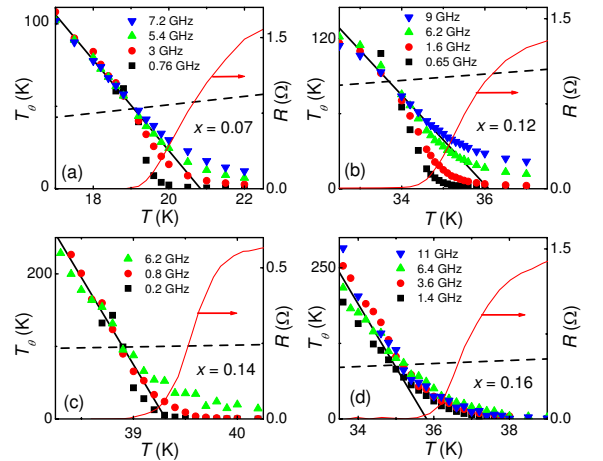


FIG. 2: The phase-stiffness temperature for the film with (a)  $x=0.07$ , (b)  $x=0.12$ , (c)  $x=0.14$ , and (d)  $x=0.16$ . The dashed straight line represents  $(8/\pi)T$ . The solid straight line gives the bare phase stiffness in the XY model, while it gives the mean-field superfluid density in the GL theory. In each panel, the dc resistance was given by red solid curves.

completely for  $x=0.16$ .  $T_c^R$  for  $x=0.16$  was close to  $T_c^0$  rather than  $T_{\text{BKT}}$ , suggesting that the mean field critical temperature  $T_{\text{MF}}$  is close to  $T_c^0$ . Thus, our results were qualitatively similar to the prediction of Emery and Kivelson<sup>13</sup> in the sense that  $T_c$  is bounded by  $T_{\text{BKT}}$  (UD region) or  $T_{\text{MF}}$  (overdoped region), although the estimation of  $T_{\text{MF}}$  in the UD region was considerably different, as will be discussed later.

In the dynamic scaling analysis of the fluctuating complex conductivity,  $\sigma_{\text{H}}(\omega)$ , which was pioneered by Booth *et al.*<sup>2</sup>, both the magnitude,  $|\sigma_{\text{H}}|/\sigma_0$ , and the phase,  $\phi_{\sigma}(\equiv \tan^{-1}[\sigma_2^{\text{H}}/\sigma_1^{\text{H}}])$ , of  $\sigma_{\text{H}}(\omega)$  are used as scaled quantities. The advantage of this method is that the data collapse to a single curve as a function of a reduced frequency,  $\omega/\omega_0$ , can be achieved without assuming any relationship between two scaling parameters,  $\sigma_0$  and  $\omega_0$ , in contrast to other scaling analyses<sup>3,4,5</sup>. Note that  $\sigma_0$  and  $\omega_0$  are obtained independently in our analysis. Thus, we can begin by checking the following hypothesis of the dynamic scaling theory<sup>1</sup>,

$$\sigma_{\text{H}}(\omega) \approx \xi^{z+2-d} S(\omega \xi^z), \quad (2)$$

where  $S(x)$  is a complex universal scaling function,  $\xi$  is a correlation length which diverges at  $T_c$ ,  $z$  is a dynamic critical exponent, and  $d$  is an effective spatial dimension. Figure 3 shows that both  $|\sigma_{\text{H}}|/\sigma_0$  and  $\phi_{\sigma}$  were scaled successfully over a wide range of frequencies for all the films, confirming that the critical dynamics suggested by Eq. (2) were indeed observed. The comparison of the experimentally obtained scaling functions with the Gaussian forms calculated by Schmidt<sup>16</sup> suggested that the 2D Gaussian-like behavior in the UD region changed into the 3D Gaussian-like behavior near  $x=0.16$ .

Equation (2) suggests that both  $\sigma_0$  and  $\omega_0$  behave as functions of  $\xi$  in a critical region, where  $\sigma_0 \propto \xi^{z+2-d}$  and  $\omega_0 \propto \xi^{-z}$ . According to the BKT theory<sup>14,15</sup>,  $\xi_{\text{KT}}$  diverges with  $\exp[b/\sqrt{\epsilon}]$  in the critical region,  $T_c < T \ll T_c^0$ , where  $\epsilon \equiv T/T_c^{\text{scale}} - 1$  and  $b$  is a numerical constant. Note that  $\sigma_0 = 1/\omega_0 \propto \xi^2$  for the relaxational 2D system with  $z=2$ <sup>1</sup>. In fact, we confirmed that both  $\sigma_0$  and  $\omega_0$  for  $x=0.07$  showed the same exponential singularity as  $\xi_{\text{KT}}^2$  with  $b=0.215$  in the range of  $\epsilon$  from 0.01 to 0.1, as shown in Figs. 4(a) and 4(b). With increasing  $x$  up to 0.14, we found that the range of  $\epsilon$  where  $\sigma_0$  (or  $\omega_0$ ) agreed with  $\xi_{\text{KT}}^2$  became narrower and shifted to lower temperatures. Such behaviors were also consistent with the BKT theory<sup>15</sup>, since  $\sigma_0$  (or  $\omega_0$ ) is rather dominated by free vortices than  $\xi_{\text{KT}}^2$  at higher temperatures, due to a screening effect by thermally activated free vortices.

In the BKT theory,  $\sigma_0\omega_0$  gives  $T_{\theta}$  in the high-frequency limit,  $T_{\theta}^0$ , which is sensitive to the surviving bound pairs of vortices above  $T_{\text{BKT}}$ <sup>15</sup>. As shown in Fig. 4(c), we found that  $\sigma_0\omega_0$  decreased with increasing  $T$  more quickly at larger  $x$ . This suggests that the temperature region of the prominent phase fluctuation became narrower with hole doping, in contrast to a recent Nernst experiment<sup>17</sup> which showed a steeper increase of the onset temperature of the Nernst effect than  $T_c$  with increasing hole doping. When

we roughly estimated  $T_{\text{MF}}$ , based on an expectation that  $\sigma_0\omega_0 \approx 0$  at  $T_{\text{MF}}$ , we found that  $T_{\text{MF}}$  was too small to cover the pseudogap region, as was previously reported by Corson *et al.*<sup>2</sup>. These results strongly suggested that most of the anomalous Nernst signal should be attributed to other origins than the superconducting fluctuation, as was suggested by some recent theoretical works<sup>18</sup>.

Moreover, the observed reduction of  $T_c$  due to the phase fluctuation ( $T_{\text{BKT}}/T_{\text{MF}} \sim 0.7, 0.9$  for  $x=0.07, 0.12$ , respectively) corresponded to the superconducting film with a very high sheet resistance  $R_{\text{sq}} (\sim 3\text{--}5 \text{ k}\Omega)$ <sup>19</sup>. Using a relation  $R_{\text{sq}} = \rho_{\text{dc}}/D_s$ , we found that  $D_s \sim 10 \text{ \AA}$ . Thus, each of the  $\text{CuO}_2$  planes seemed to be decoupled<sup>1,20</sup>. Note that the screening length for each superconducting sheet,  $\lambda_{\perp} (= \lambda^2/D_s)$ , where  $\lambda$  is a bulk penetration depth, was larger than 10 nm in this case, which satisfied the BKT criterion that  $\lambda_{\perp} \gg L$ , where  $L$  is the sample size. In addition,  $d_s$  is given by a sum of the decoupled superconducting layers with the thickness of  $D_s$ . Thus,  $d_s$  will be smaller than  $t$ , as we assumed in the estimation of  $T_{\theta}(T)$  shown in Fig. 2.

We found that the critical behavior for  $x=0.16$  was very different from that for  $x=0.07\text{--}0.14$ , as shown in Figs. 4(d) to 4(f). In particular, the dimensionality of  $x=0.16$  was found to be three, in contrast to the 2D-XY behavior of  $x=0.07\text{--}0.14$ , as shown by the plots of  $\sigma_0\omega_0 (\propto \epsilon^{\nu(d-2)})$  in Fig. 4(f), where  $\nu$  is a static critical exponent. We also confirmed that the critical exponents for  $x=0.16$  agreed very well with those for the relaxational 3D-XY model with  $\nu \approx 0.67$ ,  $z \approx 2$ , and  $d=3$ <sup>21</sup>. These results clearly suggest that the universality class in the phase diagram of LSCO changes from 2D-XY to 3D-XY with hole doping.

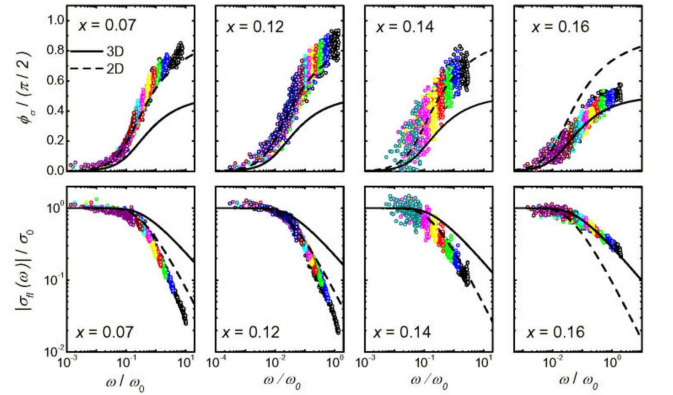


FIG. 3: Scaled curves of  $\phi_{\sigma}$  (upper panels) and  $|\sigma_{\text{H}}|$  (lower panels) for the measured LSCO film.  $\sigma_{\text{H}}(\omega)$  was obtained by subtracting the normal-state conductivity at 32 K ( $x=0.07$ ), 38 K ( $x=0.12$ ) and 40 K ( $x=0.14, 0.16$ ), respectively. Data for  $x=0.07$  span the frequency range 0.2~7 GHz at reduced temperatures  $\epsilon=0.01\sim 0.5$ , while those for  $x=0.16$  span 0.2~2 GHz at reduced temperatures,  $\epsilon=0.002\sim 0.08$ . The solid (dashed) lines are the 3D (2D) Gaussian scaling functions.

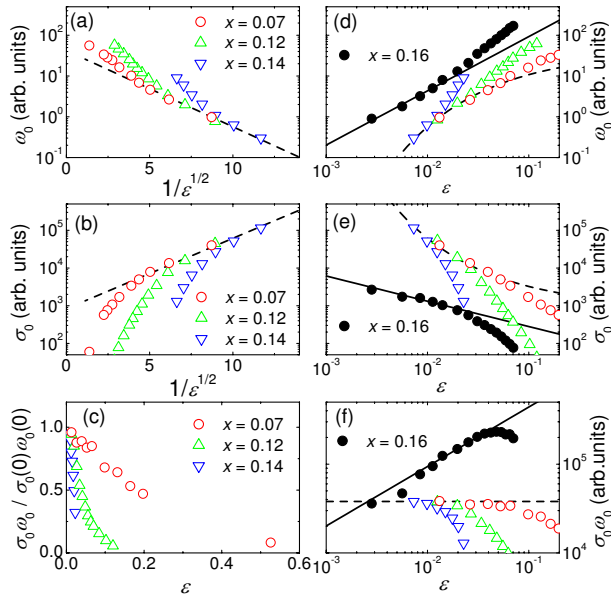


FIG. 4: (a)  $\omega_0$  and (b)  $\sigma_0$  as a function of  $1/\sqrt{\epsilon}$  for  $x=0.07$  to  $0.14$ , where  $\epsilon = T/T_c^{\text{scale}} - 1$ . The dashed line is (a)  $\xi_{\text{KT}}^{-2}$  and (b)  $\xi_{\text{KT}}^2$ . (c)  $\sigma_0\omega_0$  vs  $\epsilon$  for  $x=0.07$  to  $0.14$ . (d)  $\omega_0$ , (e)  $\sigma_0$  and (f)  $\sigma_0\omega_0$  as a function of  $\epsilon$  for  $x=0.07$  to  $0.16$ . The solid line is (d)  $\epsilon^{1.33}$ , (e)  $\epsilon^{-0.67}$  and (f)  $\epsilon^{0.67}$ . The dashed line is (d)  $\xi_{\text{KT}}^{-2}$ , (e)  $\xi_{\text{KT}}^2$  and (f) the behavior expected in  $d=2$ . Note that the absolute values of the plots in all the panels except for (c) are unimportant, since they include arbitrary proportional coefficients.

What is the origin of the dimensional crossover from 2D-XY to 3D-XY? One of candidates is the increase of the interlayer coupling (probably Josephson coupling) with hole doping<sup>1,20</sup>. However, this effect seems to ap-

pear more gradually with hole doping, in contrast to the different behavior between  $x=0.14$  and  $0.16$  shown in Figs. 3 and 4(f). Another candidate is the effect of the quantum critical fluctuation near QCP. In this case, the 2D-3D crossover can be regarded as the classical-to-quantum crossover near QCP<sup>7</sup>. A detailed study for further overdoped LSCO is needed to settle this issue.

Finally, we emphasize that all the above results rule out the possibility of the distribution of  $T_c$  due to disorders in the sample. If there is a broad distribution of  $T_c$  in the sample,  $\sigma_2$  will be greatly suppressed, leading to a smaller  $T_\theta$ , and the dynamic scaling of  $|\sigma|$  and  $\phi_\sigma$  will fail below a certain temperature, suggesting that  $T_c^{\text{scale}}$  is higher than  $T_c^R$ . In fact, these features have been observed for NbN films with a non-negligible distribution of  $T_c$ <sup>12</sup>, while all of the four LSCO films used for this study did not show them, as shown in Figs. 2 to 4.

In conclusion, a systematic study of the critical dynamics of  $\sigma_H(\omega)$  for LSCO thin films with  $x=0.07$  to  $0.16$  has been performed for the first time. All the results clearly provide evidence for the BKT transition in the nearly decoupled  $\text{CuO}_2$  layers of underdoped LSCO. With increasing hole doping, the 2D-XY behavior in the UD region changes into the 3D-XY behavior near  $x=0.16$ , indicating that the universality class in the phase diagram of LSCO is changed by hole doping.

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